E ects of D isorder on Coexistence and Competition between Superconducting and Insulating States

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We study elects of nonmagnetic in purities on the competition between the superconducting and electron-hole pairing. We show that disorder can result in coexistence of these two types of ordering in a uniform state, even when in clean materials they are mutually exclusive.

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I. INTRODUCTION

At low temperatures, many metals undergo a transition into a state with a gap in the single-electron excitation spectrum and become either superconductors or insulators with a periodic modulation of the electron charge or spin density. The insulating and superconducting (SC) orders inhibit each other by reducing the fraction of the Fermi surface available for the gap of the competing phase. The balance between the two phases is very sensitive to the Fermi surface shape and can be changed by, e.g., pressure, doping or magnetic eld.

Nonetheless, in a surprisingly large number of materials the SC and insulating states coexist. 1,2 This paper is focused on the coexistence of superconducting and charge density wave (CDW) states, observed in, e.g., layered transition m etal dichalcogenides 2H -N bSe and $2H - TaS_2 r^{3,4,5}$ the quasi-one-dim ensional compound NbSe₃, ⁶ tungsten bronzes A_xW O₃, ^{7,8} and quarter-lled organic materials.9,10 One of the best studied and best characterized CDW superconductors is the transition m etal dichalcogenide $2H - NbSe_2$. At $T_d = 33.5$ K this compound undergoes a second-order phase transition to an incommensurate CDW state, 11,12 which is likely driven by the nesting of a part of the Fermi surface. 13,14 The resistivity, however, remains metalliclike down to $T_c = 72 \text{ K}$, at which this material becomes superconducting, 4,5 and the superconductivity coexists with the CDW modulations. The coupling between the CDW and SC order param eters, resulting from the com petition between these two states, was observed in a num ber of experim ents. Thus, the suppression of the charge density modulation by pressure and hydrogen intercalation results in an increase of T_c, 5,16,17 A similar intemplay between the CDW and SC states upon applied pressure and doping is observed in NbSe3 and tungsten bronzes.6,7,8

In this paper we adopt a rather general, though simplied, viewpoint on the interplay between the SC and CDW states. We assume that it originates from the competition between two dierent Fermi surface instabilities: the instability towards the electron pairing, which gives

rise to superconductivity, and the instability towards the electron-hole (or excitonic) pairing. Here, we focus primarily on the elects of quenched disorder on this competition. We show that even in the worst case scenario', when the two states compete over the whole Ferm i surface and therefore, in absence of disorder, are mutually exclusive, disorder stabilizes a uniform state, in which superconducting and insulating order parameters coexist. While having no elect on the superconducting phase, nonmagnetic disorder tends to close the CDW gap before completely suppressing the corresponding order parameter. Disorder induces low-energy states by breaking some of the electron-hole pairs. The released electrons and holes can subsequently form Cooper pairs, resulting in the coexistence of the two phases.

W hile in usual s-wave superconductors, nonm agnetic impurities have little e ect on the transition tem perature, 18 experim ents on electron irradiated transition metal dichalcogenides have shown strong dependence of T_c on the concentration of defects. 19 This was attributed to the interplay between the SC and CDW orderings: Similarly to e ect of pressure, 5,6 disorder strongly suppresses the CDW state, which results in the observed increase of the SC critical tem perature. Theoretically, the combined e ect of the CDW modulation and disorder on the pairing instability have been studied in Ref. [20], where an increase of T_c was found. However, in that paper the amplitude of the CDW modulation was assumed to be xed, which is clearly insu cient in view of the strong suppression of the CDW state by disorder. In this paper we solve self-consistency equations for both SC and CDW order parameters, which allows us to study the interplay between these two dierent orders and obtain the tem perature versus disorder phase diagram of CDW superconductors.

The remainder of the paper is organized as follows: In Sec. II we form ulate an elective model describing the interplay between the superconducting and excitonic pairing. The self-consistency equations for the two order parameters are derived in Sec. III and in Sec. IV we analyze the phase diagram of the model. In Sec.V we discuss the electron-hole symmetry underlying the model and its

consequences for the phase diagram . Finally, we conclude in Sec. VI. The details of the derivation of the e ective model can be found in Appendix A.

II. THE MODEL

In the following we consider the microscopic H amiltonian

describing two types of ferm ions, one with hole-like dispersion (a-electrons) and another with electron-like dispersion (b-electrons), $"_{j=a;b}$ (k) = (k₽ k^2)=2m (~ = 1), where $= k_F^2 = 2m$ denotes the chemical potential (see Fig. 1). Here, in comparison with the models generally used to represent CDW systems, two nested parts of a single Ferm i surface are replaced by two spherical Ferm i surfaces m atching at the Ferm i wave vector k_F . The excitonic insulator (EI) state is the condensate of pairs form ed by b-electrons and a-holes (or vice versa) with the zero totalm om entum . 21 It is an analogue of the condensate of electron-hole pairs with the total momentum ~Q, where Q is a nesting wave vector, appearing in the CDW state.

The disorder potential U (x) encapsulates the e ect of non-magnetic impurities in the system. Here, we assume that the latter is drawn at random from a Gaussian distribution with zero mean and variance given by

$$HJ(x)U(y)i = \frac{1}{2} (x y);$$
 (2)

where is the inverse scattering time and $_{\rm F}$ = m $k_{\rm F}$ = 2 2 is the density of states at the Ferm ienergy. For simplicity we have assumed the electron and hole electron asses to be equal.

The interaction term characterized by the coupling strength g_1 describes the attraction between electrons of the same type (e.g. due to the phonon-exchange), while the g_2 term describes the (Coulomb) repulsion between the a- and b-electrons ($g_1;g_2>0$). The attraction between electrons favors s-wave superconductivity, while the second interaction leads to an attraction between electrons and holes and vice versa, favoring the EI state. Here, we neglect the inter-band electron transitions due to scattering o in purities and electron-electron interactions, so that the numbers of the a- and b-electrons are separately conserved and xed by the chemical potential. Such terms will formally destroy long-range order of the EI phase, corresponding to the suppression of the

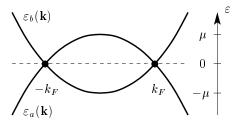


FIG. 1: Schem atic picture of the hole-like (a) and electron-like (b) bands.

long-ranged CDW order, due to the pinning of the CDW phase by random ly distributed in purities. However, for the essentially short-length-scale physics we shall discuss, these e ects may be neglected. In the absence of disorder, the same model (1) has been employed to study the competition between SC and EI states for an arbitrary ratio of electron and hole densities. The e ect of disorder on the EI state alone has been considered in the sem inalwork of Ref. [23], where the analogy of the problem to an s-wave superconductor in presence of magnetic impurities. Was drawn.

The particular ferm ion-ferm ion interactions considered in (1) { attraction between electrons of the same type and repulsion between the a-and b-electrons { open the possibility to have simultaneously both superconducting and insulating instabilities. A more realistic starting point would be a model with attractive phonon-mediated interactions and Coulomb repulsion between all types of electrons. However, it is possible to demonstrate that, since the former are retarded, while the latter is practically instantaneous, the SC and EI order parameters turn out to have a very di erent dependence on the M atsubara frequency!. This is clearly shown in Fig. 2: The SC order param eter is large at small frequencies, while at higher values, it decreases in magnitude and nally changes sign when! is of the order of the phonon frequency 0.25 By contrast, the EI parameter is large at high frequencies and has a dip for j! j < 0. In other words, the dierence in frequency scales of the attractive and repulsive interactions allows both instabilities to be present simultaneously. Furtherm ore, in the weak coupling lim it and for a weak disorder, i.e. frequency dependence of the two order param eters can be found separately for! and ! & 0. Furtherm ore, it can be shown that the self-consistency equations for the order parameters at ! = 0 coincide with the ones obtained from the model (1), which therefore can be interpreted as an e ective interacting model. Technical details together with the frequency dependence of the two order param eters and the explicit expressions for the coupling constants q₁ and q₂ in terms of the Coulomb and electron-phonon couplings can be found in appendix A.

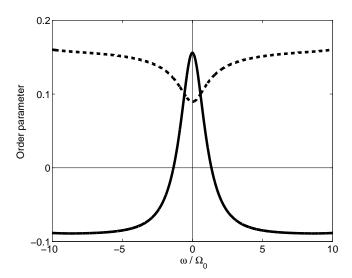


FIG. 2: The dependence of the superconducting (solid line) and excitonic (dashed line) order parameters on the M atsubara frequency! (see appendix A for details).

Four order param eters describing the SC and EI states can be introduced by m eans of the following anomalous averages

$$_{1a} = g_1 h_{a"a\#i}$$
 $_{1b} = g_1 h_{b"b\#i}$ $_{2"} = g_1 h_{a"b"i}$ $_{2\#} = g_2 h_{a\#b\#i}^{Y}$:

Since the num bers of the a-and b-ferm ions are separately conserved, for hom ogeneous states, we use the global gauge transform ation

to m ake the SC order param eters, $_{1a}$ and $_{1b}$, real and positive. M oreover, as electrons and holes are characterized by the same dispersion, we can require, without a loss of generality, that

$$_{1a} = _{1b} = _{1} > 0$$
:

In case of a spin-independent interaction, as in (1), singlet and triplet exciton pairs are degenerate in energy. This gives rise to a large symmetry class of transform ations for the EI order parameter $_2$. In reality, however, this degeneracy is lifted by Coulomb exchange interactions and inter-band transitions. Therefore, we will assume the exciton pairs have zero total spin, i.e. $_{2"}$ = $_{2\#}$ = $_{2}$.

Finally we note that, when $_1$; $_2 \notin 0$ and $_2$ has an imaginary part, a pairing of electrons of dierent types, $_{1ab} = _{gh} _{a"} _{b\#} i = _{gh} _{b"} _{a\#} i$, may be present. However, one can show the energy of the state with coexisting SC and EI orders to be the lowest for real $_2$, in which case $_{1ab} = 0$.

By analogy with the case of magnetic impurities in swave superconductors, restricting attention to the limit in which the disorder potential imposes only a weak perturbation on the electronic degrees of freedom (), the mean eld (saddle-point) equations together with the self-consistency equations for the EI and SC order parameters can be obtained using the diagram matic technique. However, we will not it more convenient to use a path-integral approach. This will also allows us to obtain straightforwardly an expression for the average free energy.

The quantum partition function, $Z = tr[e^{-H^2}]$, where = 1=T, can be expressed as a coherent state path integral over ferm ionic elds. In order to facilitate the averaging of the free energy over the disorder potential (2), it is convenient engage the replica trick:²⁶

$$F = \frac{1}{n} h \ln Z i = \frac{1}{n} \lim_{n \to \infty} \frac{h Z^{n} i}{n} :$$

Once replicated, a Hubbard-Stratonovich transform ation can be applied to decouple the interaction terms in the Hamiltonian. As a result, one obtains:

Here, om itting the replica indices for clarity, the ferm ion eld is arranged in a Nambu-like spinor, $^{T}=(_{b^{"}};_{a^{"}};_{b^{\#}}^{Y};_{a^{\#}}^{Y})$, in such a way the single quasiparticle Ham iltonian takes the following form:

$$\hat{H} = \hat{p}_{3} + U(x)_{3} + I_{1} + I_{2} + I_{3};$$
 (3)

where, $\hat{p} = r_x^2 = 2m$ and the Paulim atrices c and c (c = 1;2;3) act, respectively, in the particle-hole and the b;a subspace.

The ensemble average over the quenched random potential distribution $_{\rm R}$ (2) induces a time non-local quartic interactions, dx ($_{\rm 0}$ d $^{\rm y}$ $_{\rm 3}$) , which can be decoupled by means of a Hubbard-Stratonovich transform ation with the introduction of a matrix eld, (x), local in real space, and carrying replica, Matsubara (! $_{\rm n}$ = (2n+1) =) and internal (particle-hole and b;a) indices. Integrating over the Fermionic elds , one obtains the ensemble averaged replicated partition function:

$$Z$$
 Z $bZ^ni=$ $D_{1}D_{2}$ D_{6} F ;

where F is the free energy of the system

$$F = \int_{0}^{Z} dx dx 2 \frac{\frac{2}{1}}{g_{1}} + 2 \frac{\frac{2}{2}}{g_{2}}$$

$$tr \ln \hat{G}^{1} \frac{F}{g_{2}} dx tr [(x)]_{3}^{2} (4)$$

and \hat{G} is the quasi-particle m atrix G reen function in the presence of disorder:

$$\hat{G}^{1} = i!_{n} + \hat{b}_{3} + 1 + 2 + 1 + 2 + 3 + 4 = 0$$
 (x): (5)

The matrix eld (x) represents the contribution of the non-magnetic impurity interaction to the self-energy.

The saddle-point associated with the action (4) obtained by variation with respect to the self-energy ,

$$(x) = \frac{1}{2} \sinh \hat{\mathbf{G}} \dot{\mathbf{x}} \dot{\mathbf{$$

can be solved in the lim it ; $_1$; $_2$, when , $_1$ and $_2$ can be considered hom ogeneous. In this lim it, which is compatible with the self-consistent Born approximation, the Green function (5) is diagonal in frequency and momentum space and can be explicitly inverted:

$$G_{!_{n},p} = \frac{i \rlap{.}^{1}_{n} + p_{3} + n_{1} + n_{2} + n_{3} + n_{1}}{\rlap{.}^{1}_{n} + n_{2} + n_{3} + n_{3} + n_{3} + n_{3}} :$$

Here, we have de ned the 'renorm alized' expressions for the frequency and order param eters:

From the above equations of ${\tt m}$ otion, one ${\tt m}$ ay deduce that

$$\frac{\mathbf{t}_{n}}{\sim} = \frac{\mathbf{t}_{n}}{\mathbf{t}}; \tag{7}$$

or, in other words, that in the weak disorder lim it non magnetic impurities do not suppress s-wave superconductivity (Anderson theorem , 18) while, introducing the parameters u = $\frac{1}{2}$, and = $\frac{1}{2}$,

$$\frac{!_{n}}{2} = u \quad 1 \quad \frac{p}{1 + u^{2} \left(1 + \frac{2}{1} = !_{n}^{2}\right)} \quad : \quad (8)$$

F inally, the self-consistency equations for the SC and EI order parameters can be found m in m i

$$_{1;2} = \frac{_{1;2}}{} \times \frac{X}{4 \frac{_{1;2}}{_{1;2} + _{2;1}^{-2} + _{2;2}^{-2}}} : (9)$$

Here, $_{1;2}=g_{1;2}$ F represent dim ensionless coupling constants. Note that, as in conventional BCS theory, the integral over momentum can be performed by making use

of the identity R dp=(2) 3 = R d . Em-ploying Eq. (8), the self-consistency equations can then be rewritten in the form

$$\frac{1}{1} = -\frac{X}{1} + \frac{1}{1} + \frac{1}{1} + \frac{1}{1} = \frac{1$$

C om bining together equations (6) with (10), we are now able to discuss the $\,$ nite and zero tem perature m ean- eld phase diagram $\,$ associated with the m odel (1).

IV. PHASE DIAGRAM

A. Tem perature versus disorder phase diagram

In the absence of disorder (i.e. = 0 and u = ! $_{\rm n}$ = $_2$), one m ay note that, except for di erent coupling constants, the two self-consistency equations (10) are identical. Therefore, since they cannot be satis ed simultaneously, even though the SC and EI instabilities can occur simultaneously, in clean materials the corresponding orderings are mutually exclusive. For $_1 > _2$ the system becomes superconducting below

$$T_1 (= 0) = \frac{E}{2} 2_0 e^{1 = 1};$$
 (11)

where $_0$ is the frequency cuto and $_{\rm E}$ ' 1:78 is the Euler constant while, for $_2$ > $_1$, the transition into the EI state occurs at

$$T_2 (= 0) = \frac{E}{2} 2_0 e^{1=2} :$$
 (12)

Since charged non-m agnetic im purities act as electronhole pair breaking perturbations, while they do not affect the SC state, for $_1 > \ _2$ the SC state dom inates at any disorder strength $\,$ and the EI state never appears. On the other hand, for $_2 > \ _1$, the EI phase is energetically more favorable at weak disorder, becomes suppressed for larger values of , and eventually gives way to superconductivity. Non-m agnetic impurities suppress the EI state in exactly the same way as magnetic impurities suppress the SC state. 23,24 Therefore, one can infer that the dependence of the EI transition temperature T_2 on the disorder strength is described by the standard Abrikosov-G or kov expression:

$$\ln \frac{T_2(0)}{T_2()} = \frac{1}{2} + \frac{1}{2 T_2()} = \frac{1}{2} : \quad (13)$$

At some critical disorder strength , the EI and SC transition temperatures eventually coincide T_2 () = T_1 (= 0) = T and, for > , the system becomes superconducting at the (-independent) temperature T_1 given by Eq. (11).

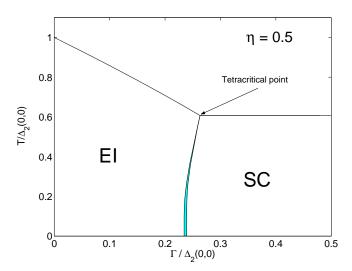


FIG .3: The tem perature vs disorder strength phase diagram of the m odel Eq.(1) for $_1^{\ 1}$ $_2^{\ 1}=0.5$. The dimensionless disorder strength is = $_2$ (T = 0; = 0) and tem perature is measured in units of T_{c2} (= 0). The EI and SC state are separated by a thin domain, in which the two order parameters coexist.

One can therefore wonder in what way, at temperatures lower than T , the transition between the EI and SC states takes place. In Fig. 3, the tem perature versus disorder phase diagram is shown for values of the coupling constants such that $= \begin{bmatrix} 1 \\ 1 \end{bmatrix}$ = 0.5. The pure EI and SC states are separated by a very thin region located in the < and T < T region of the phase diagram, where the two order param eters coexist. The three ordered phases (EI, SC, and EI+SC) and the hightem perature disordered phase merge at the tetracritical point (;T). The boundaries between the coexistence region and the two pure phases are critical lines of second order transitions although, due to the very small width of the coexistence region, the evolution of one pure phase into another is close to being of rst-order. This will be further discussed in Sec. V.

At the set critical line T_1 () separating the pure EI phase from the mixed EI+SC phase, one has $_1$! 0 and $_2$ 6 0. In the $_1$! 0 limit, the self-consistency equations (10) simplify to the expressions

$$\frac{1}{1} = 2 T_1 \frac{X}{!_n > 0} \frac{u}{!_n + u^2}$$

$$\frac{2}{2} = 2 T_1 \frac{X}{!_n > 0} \frac{1}{1 + u^2} :$$
(14)

The second critical line T_2 () separates the m ixed state from the pure SC state and is obtained by instead taking the lim it $_2$! 0 for nonzero $_1$. In this case, one can approxim ate

u'
$$\frac{!_n}{2}$$
 1+ $\frac{p}{!_n^2 + \frac{2}{1}}$;

whereupon Eqs. (10) take the form

$$\frac{1}{1} = 2 \quad T_{2} \qquad P \qquad \frac{1}{1 \cdot 2 + 2 \cdot 2} \\ \frac{1}{2} = 2 \quad T_{2} \qquad X \qquad 1 \\ \frac{1}{1 \cdot 2} = 2 \quad T_{2} \qquad P \qquad \frac{1}{1 \cdot 2 + 2 \cdot 2 \cdot 1} :$$
(15)

Note that the Elorder parameter 2 appears at temperatures lower than the \upper" T_2 () given by Eq.(13), and disappears below the \lower" T_2 (), given by Eq. (15). Figure 3 shows that $_1$ (at which the SC ordering sets in at T = 0) and $_2$ (at which the EI ordering is destroyed at T = 0) are smaller than the disorder strength at the tetracritical point . Therefore, in the interval , the system passes through three con-2 < < secutive phase transitions as the tem perature decreases: Firstly the system becomes an excitonic insulator, then it enters the mixed phase with the two coexisting order param eters, and nally the growth of the SC order param eter with decreasing temperature suppresses the EI ordering, resulting in the transition into the pure SC state $w \pm h = 0.$

B. The zero tem perature phase diagram

The zero tem perature phase diagram is shown in Fig. 4. The EI state exists only for positive (or equivalently $e = {}_{1}(T=0) = {}_{2}(T=0;=0) < 1$). The coexistence region (shaded) is connect between the two critical lines ${}_{1}() < {}_{2}()$. The system is superconducting for $> {}_{1}$, while the excitonic condensate appears for $< {}_{2}$). For small , i.e. close to the quantum critical point separating the EI and SC states in the absence of disorder, the critical disorder values can be obtained as

where = $_2$ (0;0). Therefore, the width of the coexistence region is approximately given by $_2$ $_1$ ′ 0:08 2 . For large values of , i.e. when the SC coupling $_1$

is much smaller than the EI coupling $_1$ is much smaller than the EI coupling $_2$, the coexistence region essentially coincides with the disorder intervale $^{=4}$ < < 1=2 in which the EI state is gapless. Therefore, for > 1 + 3 = 4, the superconductivity appears at the same disorder value, at which the EI becomes gapless, $_1$ = e $^{=4}$ / 0:46, while $_2$ asymptotically approaches the disorder strength at which the EI state is destroyed in the absence of superconductivity:

$$_{2}$$
 ' 1=2 e^{2} 1: (17)

W e note that, for < 1+ 3 =4, the gap in the spectrum of quasi-particle excitations at zero tem perature is nonzero for all , while for > 1+ 3 =4 it vanishes at a single point = $_1$.

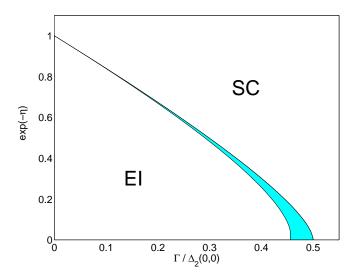


FIG. 4: The zero temperature phase diagram. Close to the quantum critical point = 0, the coexistence region is extremely thin. For 1 it practically coincides with the disorder interval, in which the EI is gapless.

This re-entrant behavior and the form of the phase diagram are similar to what was found for the spin-Peierls compound CuGeO $_3$, which upon doping shows an antiferrom agnetic ordering coexisting with spin-Peierls phase in some interval of doping concentrations. 27,28

V. EI-SC SYMMETRY

To understand why the coexistence region is so narrow, it is instructive to plot the EI and SC order parameters as functions of in the coexistence region (see Fig. 5). In the interval $_1 < _2$ the excitonic (superconducting) orderparameter decreases (increases) fast with increasing , while = $\frac{1}{_2} + \frac{2}{_2}$ stays approximately constant.

This behavior results from the symmetry between the b-and a-electrons at the quantum critical point $_1 = _2$ in the absence of disorder (= 0):

$$7 e^{i_{2}} = 2 :$$
 (18)

This transformation results is the rotation in the space of the two order parameters over the angle $2 \ [0;2]$,

$${}_{1}$$
 7 ${}_{1}$ \cos ${}_{2}$ \sin ${}_{2}$ 7 ${}_{2}$ \cos + ${}_{1}$ \sin :

At the mean-eld level, the anom alous part of the average free energy per unity of volume, hfi= hFi=V, can be easily evaluated starting from (4) and making use of

the replica trick:

hfi=
$$\frac{4}{2} \times \frac{X}{x_{n}^{2} + \frac{2}{1} + \frac{2}{2}} \times \frac{x_{n}^{2} + \text{sign}(k_{n})}{x_{n}^{2}}$$

$$\frac{2}{x_{n}^{2} + \frac{2}{1} + \frac{2}{1} + \frac{2}{2}} \times \frac{2}{1} \times$$

Let us notice that, in the absence of disorder, the free energy only depends on the total gap' = $\frac{2}{1}+\frac{2}{2}$. This follows from the fact that the generator of the E I-SC rotations $_2$ $_1$ commutes with the Hamiltonian Eq. (3) for U (x) = 0. Moreover, for $g_1=g_2$, the last term in Eq. (19) is equal to 2 $^2=g_1$ (the second term in Eq. (19) vanishes for = 0). Thus, at the quantum critical point the free energy has a Mexican hat' pro le as a function of the order parameters ($_1$; $_2$), symmetric under the rotations transforming the excitonic insulator into the superconductor. This symmetry between electron-electron and electron-hole pairing is analogous to the symmetry unifying the d-wave superconductivity and antiferrom agnetism discussed in the context of high-T $_{\rm C}$ and heavy ferm ion materials. 29,30,31

Away from the quantum critical point, and for nonzero disorder, the electron-hole sym metry is broken. Solving Eqs. (6) for $\frac{1}{2}$, and $\frac{1}{2}$, perturbatively in the disorder strength , and replacing at T=0 the sum mations over the Matsubara frequency $\frac{1}{2}$ in Eq. (19) by integrals, one can obtain an expansion of the average energy density in powers of :

$$\frac{\text{hfi}}{2_{\text{F}}} = \frac{\frac{2}{1}}{1} + \frac{\frac{2}{2}}{2} \qquad {}^{2} \text{ ln } 2 = \frac{0}{2} \qquad \frac{1}{2} \qquad {}^{2} \qquad + \frac{2}{2} = \frac{\frac{2}{2}}{3} = \frac{\frac{1}{2} \cdot \frac{2}{3} \cdot (\frac{2}{2} + \frac{4}{2})}{4} \qquad {}^{2} \qquad {}$$

D enoting the dimensionless disorder strength by = 1 and de ning the angle

$$_1 = \cos$$
 $_2 = \sin$;

we can recast Eq. (20) in the form

$$\frac{\text{hfi}}{2_{\text{F}}}, \quad ^{2} \text{ ln} - \frac{1}{2} + \frac{1}{2}\cos 2 + \frac{1}{4}(1 \cos 2)$$

$$\frac{^{2}}{12}(3 \quad 2\cos 2 \quad \cos 4)$$

$$+ \frac{^{3}}{512}(6 + 5\cos 2 \quad 6\cos 4 \quad 5\cos 6) + 0^{-4};$$
(21)

where is the geom etric mean of the EI and SC order parameters, = $\frac{P}{1-2}(0;0) = 2 \cdot 0e^{-\left(\frac{1}{1}+\frac{1}{2}\right)=2}$. The symmetry-breaking terms in Eq. (21) (that depend on the angle) are proportional to powers of and .

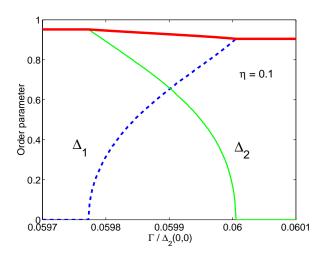
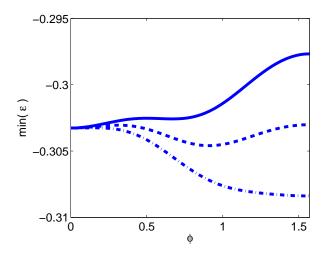


FIG .5: The plots shows the dependence of the superconducting order parameter $_1$ (dashed line) and the excitonic order parameter $_2$ (thin solid line) on the disorder strength in the region of coexistence of the two phases for = 0.1 and =



Thus, for ; 1, these terms are small and the energy has the slightly deformed M exican hat' shape with an almost at valley connecting the points $_{m\ in}$ (), at which hfi has a minimum for a given .

This is illustrated in Fig. 6 where we plot the -dependence of the minimal energy density for, respectively, = 0.234 < 1, = 0.237 (in the coexistence region) and = 0.240 > 2 (in both cases = 0.5). For < 1, the energy minimum is at = = 2 (the EI state), while at > 2 the energy minimum is for = 0

Figure 6 also illustrates the absence of rst-order transitions in the model(1). Note that = 0.237 is close to fo, at which the energies of the SC and EI states become equal: hf (0)i = hf(=2)i. The rst-order transition between the two pure states, however, does not occur, since the energy has the global minimum at some angle, such that 0 < < =2, corresponding to a mixed ground state. Furthermore, when = 0.237, the energy has a local maximum at = =2, enforcing the EI state to be metastable.

VI. DISCUSSION AND CONCLUSIONS

We discussed elects of disorder in systems with competing instabilities, such as CDW superconductors. We considered a simple model, which describes a metal with two perfectly nested electron-like and hole-like parts of the Fermi surface. In this model the interplay between the electron-electron and electron-hole pairings is very strong, as these they compete over the whole Fermi surface.

We showed that disorder can be used to tune the balance between the two competing phases and to stabilize the state, in which they coexist. The charged nonmagnetic in purities induce superconductivity by suppressing the CDW state. Such a disorder-induced superconductivity is observed in the irradiated two-dim ensional CDW m aterial 2H -TaS₂. ¹⁹ In other transition m etal dichalcogenides, e.g. 2H -N bSe2 and 2H -TaSe2, which are CDW superconductors already in absence of disorder, a small amount of irradiation-induced defects results in an enhancement of T_c. 19 Sim ilar behavior is observed in the quasi-one-dim ensional CDW material Nb_{1 x} Ta_xSe₃. In the pure NbSe3, Tc is smaller than 50 mK at ambient pressure. 16 The substitution of Nb for Ta suppresses the resistivity anomalies due to the CDW transitions, while $T_{\rm c}$ grows up to 2K at x = 0.05. The e ect of im purities in these materials is similar to that of pressure and hydrogen intercalation. 5,16,17

In agreement with these experimental ndings, the phase diagrams of our model Figs. 3 and 4, show a strong sensitivity of the ground state to disorder and the coexistence of the SC and EI states in the presence of disorder. This behavior can be easily understood and described analytically, using the Landau expansion of the free energy in powers of the EI and SC order parameters near the quantum critical point [see Eq.(20)], which we derived from the microscopic model. Disorder distorts the shape

of the energy potential and continuously shifts the position of the minimum from the point corresponding to the excitonic insulator to the point corresponding to the superconducting state, which gives rise to the coexistence of the two states.

The microscopic origin of this coexistence is the breakup of a part of the electron-hole pairs by disorder and the subsequent recombination of the released fermions into electron-electron and hole-hole pairs. In other words, disorder transforms the CDW gap in the single-electron density of states into a pseudogap, lled with states describing the broken electron-hole pairs. The SC phase develops inside this pseudogap, which resembles the behavior observed in high-T $_{\rm C}$ cuprates. 32

In addition to the disorder-induced superconductivity, resulting from the suppression of the EI state, the phase diagram of our model (see Fig. 3) shows an interesting 'inverse' e ect, namely the suppression of the EI state due to the growth of the SC order parameter with decreasing temperature. Though this re-entrance transition is just another consequence of the competition between the two types of ordering, we did not nd any reports of such a behavior in CDW superconductors in the literature. This, however, it has been observed in the quasi-one-dim ensional spin-Peierls com pound CuGeO3, where impurities induce the long range Neel ordering. 28 In this material, the interplay between the dimerized and antiferrom agnetic states allows for a sim ilar theoretical description. 27 In most CDW superconductors the CDW transition occurs at a much higher temperature than the SC transition, so that the in uence of the Cooper pairing on the CDW modulations is dicult to observe. Furtherm ore, the CDW gap only opens on a nested part of the Ferm i surface. In quasi-one-dimensional NbSe3 the fraction of the Fermi surface a ected by the CDW transition was estimated to be 0:6 at am bient pressure. In the two-dimensional 2H -N bSe₂ this fraction is apparently very small, since the gap opening actually increases the conductivity of this material¹² and the part of the Ferm i surface, where the gap opens, was not found in ARPES experim ents, 13,14,33 even though the gap value (34m eV) is known. 34 For partially gapped Ferm isurfaces the competition between the CDW and SC states is less strong, so that in 2H -N bSe2 they coexist even in absence of disorder.

While the enhancement of the SC transition temperature upon the suppression of the CDW state is well documented in many materials, the experimental situation with in uence of the superconductivity on the CDW state is less clear. On the one hand, Raman experiments on 2H-NbSe₂ show the suppression of the intensity the collective SC mode by magnetic eld with the concomitant enhancement of the intensity of the CDW modes. On the other hand, no election of the superconducting ordering below 7K and of the suppression of the SC state by magnetic eld on the CDW modulation was observed in x-ray experiments. The understanding of the behavior of 2H-NbSe₂ is complicated by the multi-sheet structure of the

Ferm i surface and the m om entum —and sheet-dependence of both order param eters. 33 The interplay between the CDW and SC states in this and other materials requires further experimental and theoretical studies.

C rucially, one m ay note that the phase diagram of the interacting system was inferred from the self-consistent Hartree-Fock approximation which captures only the mean-eld characteristics. In view of the lamentary structure of the coexistence region, the system can be susceptible to mesoscopic or sample to sample uctuations due to the quenched impurity potential. Such effects are recorded in uctuations of the eld (x) around its saddle-point or mean-eld value (as opposed to the leading term sgathered in the low-order expansion considered here). In the gapless regime, such e ects can give rise to long-ranged di usion mode contributions to the generalized pair susceptibility (cf., e.g., Ref. [37]). However, in the present case, the disorder potential in poses a sym m etry breaking perturbation on the EI phase. As such, we can expect mesoscopic uctuations due to disorder to impose only a short-ranged (i.e. local on the scale of the coherence length of the EI order param eter) perturbation on the pair susceptibility. In the vicinity of the coexistence region, where the potential for the angle

is shallow, the e ect of these m esoscopic $% \left(1\right) =\left(1\right) +\left(1\right)$

To understand the e ect of random uctuations in the coexistence region, we consider the G inzburg-Landau expansion for the ground state energy close to the quantum critical point = 0; = 0, at which the E I and SC states are degenerate. In the vicinity of this point the phase of the 'total' order parameter $_1+i_2=e^i$ is a soft mode, so that weak disorder mainly induces spatial uctuations of the phase, while the magnitude of the order parameter approximately stays constant. As in the derivation of Eq.(21), we expand the energy in powers of and disorder strength, assuming that , which is justified in the coexistence region, where $\frac{2}{}$ (see Eq.(16). Assuming that the phase varies slow by on the length scale of the correlation length $=\frac{v_F}{}$, where v_F is the Fermi velocity, we obtain

F'
$$dx = \frac{v_F^2}{6} (r)^2 + u(x) \cos 2 + hfi;$$
 (22)

where the rst term describes the blastic energy' of an inhom ogeneous state, the disorder-averaged free energy hfi is given by Eq.(21), and u(x) is the uctuating part of disorder coupled to the phase of the order param eter. Neglecting correlations on a scale smaller that the correlation length, u(x) can be approximately considered as a random—correlated G aussian variable with zero average, hu(x)i = 0, and variance

hu (x)u (y)i = A (x y)
$$A = \frac{4 \cdot 2 \cdot 2}{2k_F^3}$$
; (23)

(we om it the lengthy calculations that lead to this result). The coupling to disorder also occurs in higher orders of

the expansion, but those terms are relatively ${\bf sm}$ all and can be neglected.

Following the Im ry and M a argument, 38 we consider a large phase uctuation, e.g., a droplet of the SC phase of the spatial extent L inside the EIm atrix. Com paring the typical energy gain due to the coupling to disorder $_{\rm F}$ 1 AL 3 with the loss in the elastic energy $_{\rm F}$ v $_{\rm F}^{2}$ L, we not that the uctuation is energetically favorable for

$$L > \frac{V_F^4}{\Delta} = \frac{V_F^4 k_F^3}{2 \ 2 \ 2 \ 4} ;$$
 (24)

where we took into account that, in the coexistence region, $\frac{2}{2}$.

The crucial di erence of our model from that considered in Ref.[38] is the absence of an exact continuous symmetry. Even in the coexistence region, the minimal-energy valley connecting the SC and EI points (= 0 and = $\frac{1}{2}$) is not perfectly at. The typical amplitude of the variations of the energy density is 2 $_{\rm F}$ 2 (see Eq. (21)), resulting in the energy loss 2 $_{\rm F}$ $^2{\rm L}^3$ proportional the volume of the uctuation, which suppresses large droplets. Comparing it with the energy gain, we not

$$L^3 < \frac{A}{4}$$
: (25)

Equations (24) and (25) hold simultaneously for

$$v_F k_F <$$
 (26)

which cannot be satis ed in the weak coupling lim it. One may wonder why the condition (26) does not hold even for = = 0, where the model has a continuous symmetry. The reason is that in our model the role of disorder is two-fold. On the one hand, it couples to the order parameter, as in the random eld'model discussed in Ref.[38] and tends to destroy the ordering. On the other hand, it a ects the energy dierence between the EI and SC states and, therefore, suppresses the phase uctuations, by destroying the symmetry of the energy potential. The second e ect, which is linear in , is stronger than the rst.

Thus, the inhom ogeneity of the order parameter, resulting from typical disorder uctuations is small. The phase uctuations can also be induced by large disorder uctuations ('Lifshitz tails'), but their contribution to the free energy is exponentially small.³⁹ This justi es our mean eld treatment of disorder.

This conclusion may not hold, however, for strongly coupled CDW superconductors or for other types of disorder. Qualitatively, we expect that inhom ogeneous excitonic and superconducting order parameters may result in a broadening of the coexistence region. The local suppression of the excitonic pairing near charged in purities can give rise to the local enhancement of the superconducting order. The state with such a nanoscale phase separation, in which two competing orders alternate in

antiphase without a loss of the macroscopic coherence, can be more energetically favorable than the uniform state and, therefore, can be stabilized in a wider interval of parameters. Such a state was observed in SR experiments on doped CuGeO $_3$, which shows both spin-Peierls and antiferrom agnetic ordering. 40

In conclusion, we studied e ects of disorder on systems with competing superconducting and charge-density-wave instabilities. We showed that even in the extreme situation, when the competition takes place over the whole Ferm is urface and the superconducting and charge-density-wave phases are mutually exclusive, disorder can give rise to their coexistence in a spatially hom ogeneous state. Furthermore, disorder itself can be used as a parameter, with which one can tune the balance between competing phases. Although our model is too simple to describe the physics behind the coexistence of superconductivity and CDW (SDW) states in, e.g., high- $T_{\rm c}$ or heavy ferm ion materials, we believe that the ability of disorder to bring together incompatible phases may be important for understanding phase diagram softhese systems.

APPENDIX A:COEXISTING INSTABILITIES AND DERIVATION OF THE EFFECTIVE MODEL

In this appendix we obtain a condition under which both the SC and EI instabilities can occur simultaneously. Here, we consider more realistic interactions between electrons than those described by the model (1), namely, the phonon-mediated interaction and the Coulomb repulsion. The Coulomb repulsion counteracts the phonon-mediated attraction between electrons and suppresses the SC instability. The same holds for the instability towards the formation of the excitonic condensate with the difference that the two types of interaction now change roles: the Coulomb force favors the electron-hole pairing, while the one-phonon exchange results in a repulsion between electrons and holes. We will show that the SC and EI instabilities can coexist due to different frequency dependence of the two types of interactions.

For retarded phonon-m ediated interactions, the order param eters $_1$ and $_2$ are frequency-dependent, which complicates the solution of the self-consistency equations. We show, however, that in the weak coupling and weak disorder limit, the equations for the order parameters at zero frequency coincide with Eq. (9), which justies the model introduced in Sec. II. Moreover, we will give the explicit expressions for the coupling constants g_1 and g_2 appearing in Eq. (1).

W e describe e ective electron-electron interactions by

a non-local action

$$S_{e} = \frac{g_{e-ph}^{2}}{2}^{Z} dx d d d^{0} (x;)D (0) (x; ^{0}) + \frac{g_{c}^{2}}{2}^{Z} dx d^{2} (x;); (A1)$$

where = P ($\frac{y}{a}$ a + $\frac{y}{b}$ b) is the total electron density. The rst term is the phonon-mediated e ective attraction between electrons and D (0) is the phonon G reen function. For a single dispersionless optical phonon with the frequency $_{0}$ and the propagator D $_{1n}$ = $_{0}^{2}$ =(! $_{n}^{2}$ + $_{0}^{2}$), we have D (0) = $_{0}$ e 0 j $_{0}^{2}$ =2 for T $_{0}$. The second term in Eq. (A1) is the instantaneous C oulom b interaction. We neglect the momentum dependence of the screened electron-phonon and C oulom b couplings, which makes the electron-electron interactions local in space.

The couplings for the a and b-electrons in Eq.(A1) give rise to a large freedom in the choice of order param eters, which in reality may not be present, e.g., due to the interband scattering, which separately does not conserve the

num bers of the a and b electrons. In what follows we restrict ourselves to the anom alous averages considered in Sec. II, which, for retarded interactions Eq. (A1), are time-dependent (j = a; b and = "; #):

$$g_{e-ph}^{2}D(t) = g_{e-ph}^{2}D(t) = g_{e-ph}^{2}D(t) + g_{c}^{2}h_{i}(t)_{i}(t)_{i}(t)$$

In the frequency representation the self-consistency equations read

$${1}(!_{n}) = \frac{T}{4V} \sum_{p!_{n}^{0}}^{X} g_{e-ph}^{2} D_{!_{n}}!_{n}^{0} \qquad q_{e}^{2} \text{ tr } {}_{1}G_{p;!_{n}^{0}}$$

$${1}(!_{n}) = \frac{T}{4V} \sum_{p!_{n}^{0}}^{X} g_{e-ph}^{2} D_{!_{n}}!_{n}^{0} \qquad q_{e}^{2} \text{ tr } {}_{3} {}_{1}G_{p;!_{n}^{0}} ;$$

where the electron G reen function is given by Eq. (5).

To sim plify the algebra, we consider here only the zero tem perature case. The integration over the electron excitation energy gives

$${}_{1}(!) = \frac{1}{2} \sum_{E_{c}}^{Z_{+E_{c}}} d!^{0} \qquad {}_{1} \frac{{}_{0}^{2}}{(! \quad !^{0})^{2} + {}_{0}^{2}} \qquad {}_{2} \frac{q}{1} \frac{{}_{1}(!^{0})}{!^{0} + {}_{2}^{2}(!^{0}) + {}_{2}^{2}(!^{0})}$$

$${}_{1}(!) = \frac{1}{2} \sum_{E_{c}}^{Z_{+E_{c}}} d!^{0} \qquad {}_{2} \qquad {}_{1} \frac{{}_{0}^{2}}{(! \quad !^{0})^{2} + {}_{0}^{2}} \frac{q}{1} \frac{{}_{1}(!^{0}) + {}_{2}^{2}(!^{0})}{!^{0} + {}_{2}(!^{0}) + {}_{2}^{2}(!^{0})}$$
(A2)

where we have introduced the dimensionless coupling constants, $_1 = _F g_{e-ph}^2$ and $_2 = _F g_c^2$, and where E_c is the frequency cuto required for the instantaneous C oulomb interaction. Moreover the variables L ; $^{\sim}_1$; and $^{\sim}_2$ are dened in (6).

Although Eqs. (A 2) look at a st sight complicated, one can see that, in the limit of weak coupling and weak disorder, $_{1;2}$; $_{0} < E_{c}$, their solution can be found by making use of the fact that the order parameters $_{1}$ (!) and $_{2}$ (!) strongly vary at frequencies! $_{0}$, while 1 , 2 , and 2 are nontrivial functions of! only at much lower frequencies! , where $_{1}$ (!) and $_{2}$ (!) can be replaced by their zero frequency values. Therefore, we can solve Eqs. (A 2) in two steps: rst we not the frequency dependence of the order parameters $_{1}$ (!) and $_{2}$ (!) for arbitrary values of $_{1}$ (0) and $_{2}$ (0), and then we solve the self-consistency equations for $_{1}$ (0) and $_{2}$ (0).

It is convenient to use the dimensionless variables x =

!=0 and $y_{1;2}(x)=1;2(!)=0$ (and similarly x and $y_{1;2}(x)$), in term softwhich the set of the equations (A2) reads

$$y_{1}(x) = \begin{cases} z \\ 0 \end{cases} dx^{0} \frac{y_{1}(x^{0})}{x^{0} + y_{1}^{2}(x^{0}) + y_{2}^{2}(x^{0})}$$

$$\frac{1}{2} \frac{1}{(x + x^{0})^{2} + 1} + \frac{1}{(x + x^{0})^{2} + 1} \qquad z \qquad ;$$

where = E $_{\rm c}=_0$. We then introduce an intermediate scale X , such that $y_{1;2}=X=1$. In the interval 0 $x^0=X$, we can neglect the x^0 -dependence of the kemel of this integral equation and the functions $y_{1;2}$ (x^0) (however, $y_{1;2}$ and x^0 still do depend on x^0). In the second interval X $x^0=x^0$, we substitute $y_1=\frac{x^0}{x^0}+\frac{y_1^2}{y_1}+\frac{y_2^2}{y_2}$ by y_1 $(x^0)=x^0$ and perform the integration by parts. In this way we obtain

$$y_{1}(x) = y_{1}(x) = y_{1}(x) + \frac{1}{1+x^{2}} + \frac{1}{1+x^{2$$

where the lim its of the second integration were extended to 0 and 1, as there is convergence both at small and large frequencies.

Since, at X $y_{1;2}$, Eq. (A3) is independent of X, we can chose X = 1 (and still substitute $y_{1;2}$ (x^0) by $y_{1;2}$ (0) in the rst integral). The value of y_1 at the cuto is then given by

$$y_{1}() = \begin{cases} & u_{1} \\ & v_{1} \\ & v_{2} \end{cases} dx^{0} \frac{y_{1}(x^{0})}{x^{0} + y_{1}^{2}(x^{0}) + y_{2}^{2}(x^{0})} dx \ln x \frac{dy_{1}}{dx} ;$$

where $_2 = _2 = (1 + _2 \ln)$. For arbitrary x we have

$$y_{1}(x) = \frac{1}{1+x^{2}} \sum_{2} I(y_{1}(0); y_{2}(0))$$

$$Z \int_{0}^{1} dx^{0} \ln x^{0} \frac{d}{dx^{0}} \int_{0}^{1} \frac{1}{(x+x^{0})^{2}+1} + \frac{1}{(x+x^{0})^{2}+1} \int_{0}^{1} \frac{1}{(x+x^{0})^{2}+1} dx^{0} \int_{0}^{1} \frac{1}{(x+x^{0})^{2}+1} dx^{0} dx^{0} \int_{0}^{1} \frac{1}{(x+x^{0})^{2}+1} dx^{0} dx^{0$$

where the notation

The entertain in the notation
$$I(y_1(0); y_2(0)) = \int_0^{Z_1} dx^0 \frac{y_1(x^0)}{x^0 + y_1^2(x^0) + y_2^2(x^0)}$$

is used to stress the fact that y_1 and y_2 are assumed to be frequency independent.

In the weak coupling lim it the rst term in the righthand side of Eq. (A4), proportional to the large logarithm ' $\ln^2 y_1^2 + y_2^2$, is much larger than the second term, so this integral equation can be solved by iterations, which generate a perturbative expansion for y_1 (x). To the lowest order, the frequency dependence of the order param eter coincides with that of the kernel.²⁵

$$y_1(x) = \frac{1}{1+x^2}$$
 $y_1(0); y_2(0)$: (A 5)

Then the self-consistency equation for $_1$ (0) coincides with Eq. (9) at T = 0:

$${}_{1}(0) = {}_{1} {\overset{Z}{\underset{0}{\text{od!}}}} {\overset{\circ}{\text{d!}}} \frac{{}_{1}(!)}{{}_{1}^{2} + {}_{1}^{2}(!) + {}_{2}^{2}(!)}; \quad (A 6)$$

and the e ective coupling constant is given by

$$_{1} = _{1}$$
 $_{2} = _{1}$ $\frac{2}{1 + _{2} \ln E_{c} = _{0}}$ (A 7)

The negative term in the coupling constant describes the reduction of the attraction between electrons due to the Coulomb repulsion, but this reduction is itself reduced by the presence of the large logarithm in the denominator due to the dierence in the time scales of the retarded phonon-mediated attraction and the Coulomb repulsion. 25,41 The rst-order correction to y_1 (x), found by substituting Eq. (A5) into the integral in Eq. (A4) (as well as all higher-order corrections), leaves the form of the self-consistency equation (A 6) unchanged, but results in a small modi cation of the expression for the e ective coupling constant through 1 and 2:

$$_{1} = _{1} 1 \frac{1}{2} _{2} :$$

The frequency dependence of the excitonic insulator order param eter $_{2}$ (!) and the self-consistency equation for 2 (0) can be obtained from Eqs. (A 6,A 7) by the substitution 17 2, 17

$${}_{2}(0) = {}_{2} {}_{0} {}_{0} d! = {}_{2} {}_{0} {}_{0} d! = {}_{2} {}_{0}$$

where the e ective coupling constant 2 is to the lowest order given by

$$_{2} = \frac{2}{1 + 2 \ln E_{0}} + \frac{2}{1}$$
: (A 9)

In Fig. 2 we show the typical frequency dependence of the SC and E I order param eters, calculated for $_1 = 0.25$ and 2 = 0:1 and = 0. (Since in the absence of disorder the SC and EI states cannot coexist, we calculated $_1$ (!) assum ing $_2 = 0$ and vice versa.) The SC order param eter 1 (!) is positive at small frequencies and changes sign at ! ' 0, while the EI order param eter 2 (!) has a dip for j! j < 0. The 'separation' of the two order param eters in frequency is crucial for the coexistence of instabilities.

The necessary condition for superconductivity to appear is 1 > 0, while the instability towards the excitonic condensate occurs for $_2 > 0$. These two conditions,

$$_{1} > \frac{2}{1 + _{2} \ln }$$
 $_{1} < \frac{2}{1 + _{2} \ln }$;

hold simultaneously for

$$j j = \frac{1}{1} \frac{1}{2} < \ln \frac{E_c}{0}$$
: (A 10)

A weak disorder has little e ect on the frequency dependence of $_1$ and $_2$. However, its presence is crucial for the stabilization of the mixed state, in which the two order param eters coexist.

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